

Tri-layered Si/Co₃O₄/ZnO heterojunction for high-performance visible photodetection

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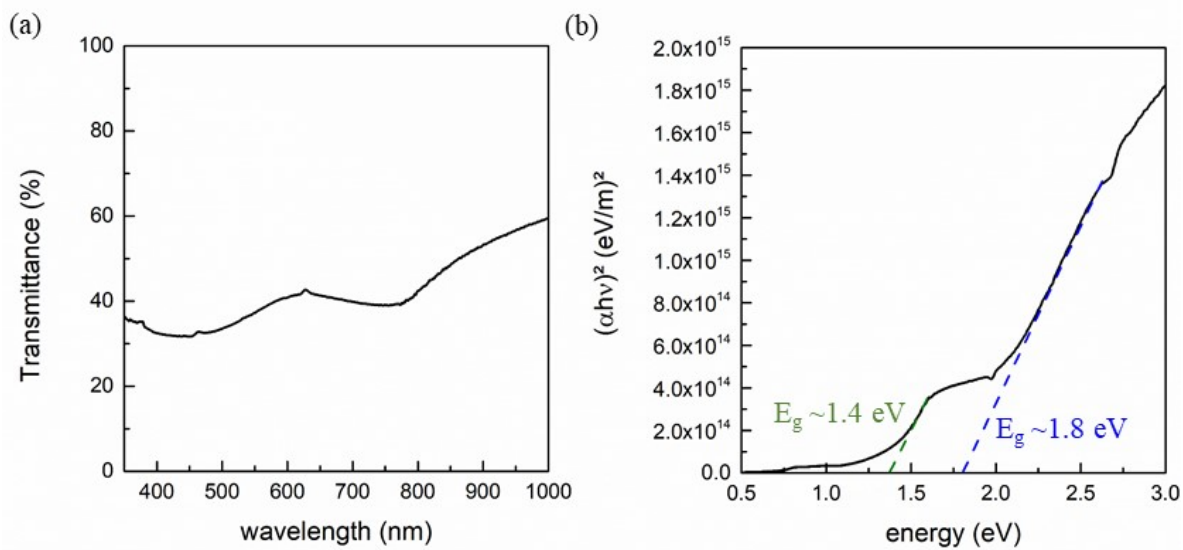


Fig. S1. Optical properties of the Co₃O₄ deposited on glass substrate. a) Transmittance spectrum versus wavelength and (b) $(\alpha h\nu)^2$ versus incident photon energy plot. Optical band gaps were determined via the linear extrapolation in Tauc method.